

IN THE TITLE

Please delete the title in its entirety and insert — A DEVICE WITH RECESSED THIN AND THICK SPACERS FOR IMPROVED SALICIDE RESISTANCE ON POLYSILICON GATES --- therein.

IN THE SPECIFICATION

B1 Please insert as a separate paragraph below the title on page 1 / This is a division of Application No. 09/386,495, filed August 30, 1999, which is a further division of Application No. 09/191,729, filed November 13, 1998. / therein.

IN THE CLAIMS

Please enter the following claims:

31. (Once Amended) A gate electrode comprising:
- an insulative layer disposed on a substrate;
 - a gate layer disposed on said insulative layer;
 - a conductive layer disposed on said gate layer, said conductive layer extending beyond edges of said gate layer;
 - thin first spacers disposed adjacent to opposite sides of said gate layer wherein said thin first spacers are recessed below said conductive layer;